

Si photodiodes

S1226 series

For UV to visible, precision photometry; suppressed near IR sensitivity

Features

Applications

Analytical equipment

Optical measurement equipment, etc.

- Suppressed near IR sensitivity
- High sensitivity in UV region (quartz glass type)
- Low dark current
- High reliability

Structure / Absolute maximum ratings

Type no.	Dimensional			Absolute maximum ratings					
	Dimensional outline/		Photosensitive	Reverse	Operating	Storage			
	Window material*	Package	area size	voltage	temperature	temperature			
				Vr max	Topr	Tstg			
			(mm)	(V)	(°C)	(°C)			
S1226-18BQ	(1)/Q	TO-18	1.1×1.1		-20 to +60	-55 to +80			
S1226-18BK	(2)/K	10-10	1.1 ^ 1.1		-40 to +100	-55 to +125			
S1226-5BQ	(3)/Q		2.4×2.4		-20 to +60	-55 to +80			
S1226-5BK	(4)/K	TO-5	2.4 ^ 2.4	F	-40 to +100	-55 to +125			
S1226-44BQ	(5)/Q	10-5	3.6×3.6	5	-20 to +60	-55 to +80			
S1226-44BK	(6)/K		3.0 × 3.0		-40 to +100	-55 to +125			
S1226-8BQ	(7)/Q	TO-8	5.8 × 5.8		-20 to +60	-55 to +80			
S1226-8BK	(8)/K	10-0	5.0 × 5.0		-40 to +100	-55 to +125			

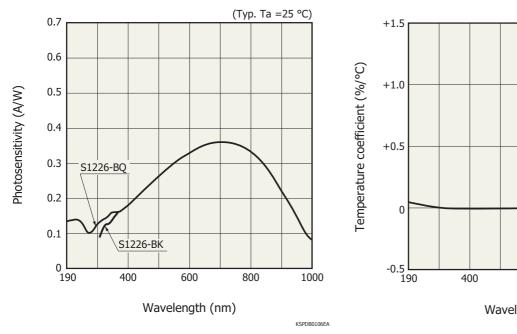
Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

* Window material, K=borosilicate glass, Q=quartz glass

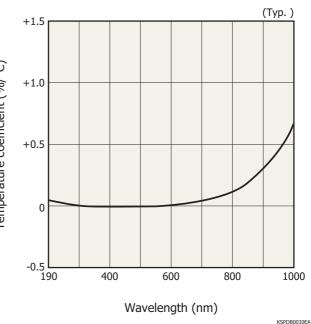
Electrical and optical characteristics (Typ. Ta=25 °C, unless otherwise noted)

Type no.	Spectral response range λ	Peak sensitivity wavelength λp	Photosensitivity S (A/W)			ty	Short circuit current Isc		Dark current ID VR=10 mV	coefficient of ID	tr Vr=0 V	Terminal capacitance Ct VR=0 V	resistance Rsh		Noise equivalent power
			2 -	200	nm	He-Ne 100 lx laser		max.	TCID	RL=1 kΩ	f=10 kHz	VR=10 mV		NEP	
	(1919)	(19.192)	λр	Min.	Тур.	633	Min.	Тур.		(1) (00)			Min.	Typ.	(14/11 1/2)
	(nm)	(nm)				nm	(µA)	(µA)	(pA)	(times/°C)	(µs)	(pF)	(GΩ)	(GΩ)	(W/Hz ^{1/2})
S1226-18BQ	190 to 1000	720	0.36	0.10	0.12	0.34	0.5	0.66	2	1.12	0.15	35	5	50	1.6 × 10 ⁻¹⁵
S1226-18BK	320 to 1000			-	-										
S1226-5BQ	190 to 1000			0.10	0.12		2.2	2.9	5		0.5	160	2	20	2.5 × 10 ⁻¹⁵
S1226-5BK	320 to 1000			-	-										
S1226-44BQ	190 to 1000			0.10	0.12		4.4	5.9	10		1	500	1	10	3.6 × 10 ⁻¹⁵
S1226-44BK	320 to 1000			-	-										
S1226-8BQ	190 to 1000			0.10	0.12		12 1	16	20		2	1200	0.5	5	5.0×10^{-15}
S1226-8BK	320 to 1000			-	-										

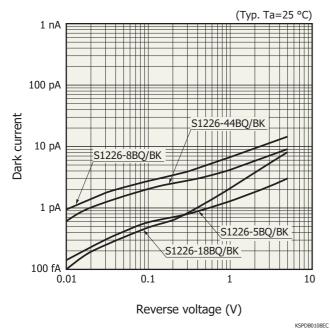
Spectral response



Photosensitivity temperature characteristic

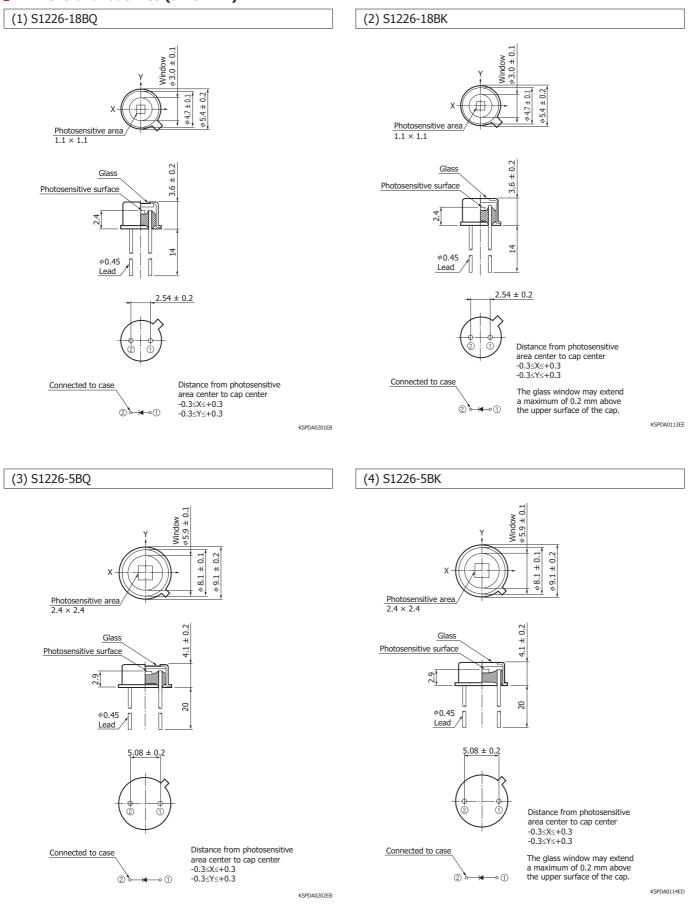


Dark current vs. reverse voltage





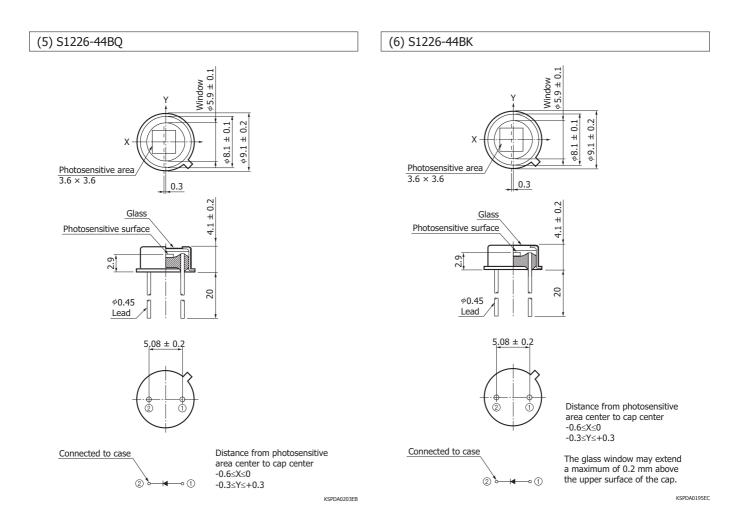


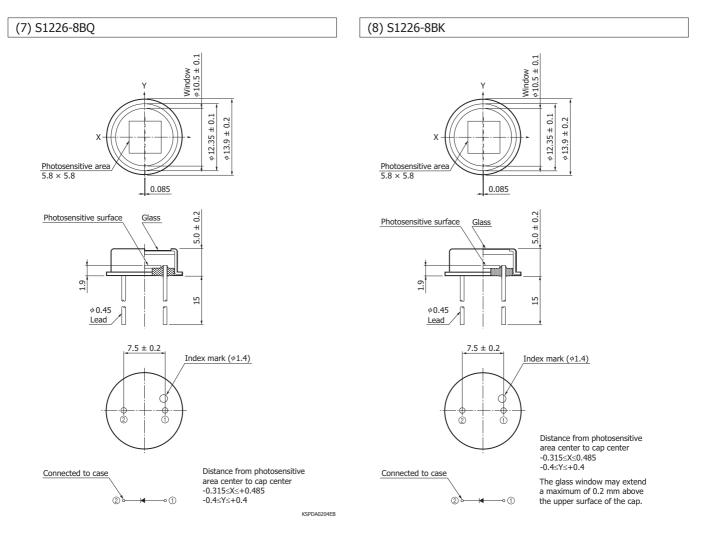


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Information described in this material is current as of November, 2013.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

Type numbers of products listed in the delivery specification sheets or supplied as samples may have a suffix "(X)" which means preliminary specifications or a suffix "(Z)" which means developmental specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use.

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